

### **Features and Benefits**

- CMOS Hall IC Technology
- Bipolar Output CMOS Multi-purpose latch
- Solid-State Reliability much better than reed switch
- Operation down to 2.5V
- Supply current down to 45µA, very low power consumption
- CMOS inverter output (no pull-up resistance)
- High sensitivity for direct reed switch replacement application

# **Application Examples**

- Solid state switch
- Magneto-electric conversion switch
- Magnet proximity sensor for reed switch replacement in low duty cycle applications

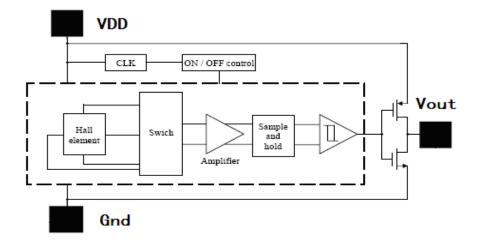


3 pin TSOT23 (suffix ST)



3 pin SIP (suffix UA)

## **Functional Block Diagram**





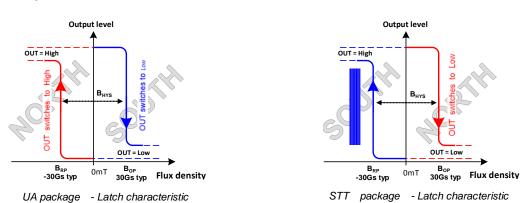
# **General Description**

The SS542 Hall effect sensor IC is fabricated from mixed signal CMOS technology. It incorporates advanced chopper-stabilization techniques to provide accurate and stable magnetic switch points.

The circuit design provides an internally controlled clocking mechanism to cycle power to the Hall element and analog signal processing circuits. This serves to place the high current-consuming portions of the circuit into a "Sleep" mode. Periodically the device is "Awakened" by this internal logic and the magnetic flux from the Hall element is evaluated against the predefined thresholds. If the flux density is above or below the  $B_{op}/B_{rp}$  thresholds then the output transistor is driven to change states accordingly. While in the "Sleep" cycle the output transistor is latched in its previous state. The design has been optimized for service in applications requiring extended operating lifetime in battery powered systems.

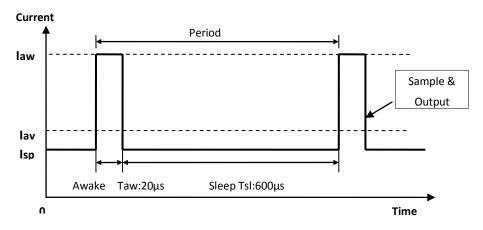
The output transistor of the SS542 switches low (turns on) when a magnetic field perpendicular to the Hall sensor exceeds the operate point threshold ( $B_{OP}$ ). After turn-on, the output voltage is  $V_{DS}$ . The device remains on if the south pole is removed ( $B\rightarrow 0$ ). This latching property defines the device as a magnetic memory. When the magnetic field is reduced below the release point,  $B_{RP}$ , the Output transistor turns off (goes high). The difference in the magnetic operate and release points is the hysteresis ( $B_{HYS}$ ) of the device. This built-in hysteresis prevents output oscillation near the switching point, and allows clean switching of the output even in the presence of external mechanical vibration and electrical noise.

The TSOT-23 device is reversed from the UA package. The TSOT-23 output transistor will be latched on in the presence of a sufficiently strong North pole magnetic field applied to the marked face.



### **Glossary of Terms**

## **Internal Timing Circuit**





## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Units
Supply Voltage	V <sub>DD</sub>	28	V
Supply Current	I <sub>DD</sub>	50	mA
Output Voltage	V <sub>OUT</sub>	28	V
Output Current	I <sub>OUT</sub>	50	mA
Operating Temperature Range	T <sub>A</sub>	-40 to 85	°C
Storage Temperature Rang	Ts	-50 to 150	°C
ESD Sensitivity	-	4000	V

<b>Operating Temperature Range</b>	Symbol	Value	Units	
Temperature Suffix "E"	T <sub>A</sub>	-40 to 85	°C	
Temperature Suffix "K"	T <sub>A</sub>	-40 to 125	°C	
Temperature Suffix "L"	T <sub>A</sub>	-40 to 150	°C	

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum- rated conditions for extended periods may affect device reliability.

## **General Electrical Specifications**

DC Operating Parameters  $T_A = 25^{\circ}$ C,  $V_{DD}$ = 2.5V to 5.5V (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Operating voltage	V <sub>DD</sub>	Operating	2.5	3	5.5	V
Supply current	I <sub>DD</sub>	Average		45		μΑ
Output Current	I <sub>OUT</sub>			1.0		mA
Saturation Voltage	V <sub>SAT</sub>	I <sub>OUT</sub> =1mA			0.4	V
Awake mode time	T <sub>AW</sub>	Operating		20		μS
Sleep mode time	T <sub>SL</sub>	Operating			600	μS

### **Magnetic Specifications**

DC Operating Parameters  $V_{DD} = 2.5$  to 5.5V (unless otherwise specified)

Package	Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
	Operating Point	B <sub>OP</sub>	T- 25%C	5	25	40	G
UA	Release Point	B <sub>RP</sub>	$Ta=25^{\circ}C$	-40	-25	-5	G
	Hysteresis	B <sub>HYST</sub>	V <sub>dd</sub> =2.75V DC		40		G
	Operating Point	B <sub>OP</sub>	T 25%C	-40	-25	-5	G
SO	Release Point	B <sub>RP</sub>	Ta=25°C V <sub>dd</sub> =2.75V DC	5	25	40	G
	Hysteresis	B <sub>HYST</sub>			40		G

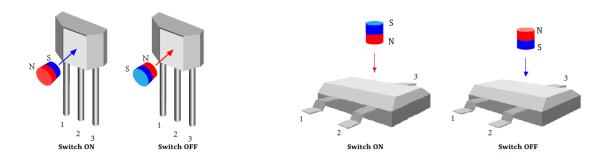


## **Output Behavior versus Magnetic Pole**

DC Operating Parameters $TA = -40^{\circ}C$ to $150^{\circ}C$ , $V_{DD} = 2.5$	to 5.5V (unless otherwise specified)
De Operating Latanieters $TA = -40$ C to 150 C, $v_{DD} = 2.5$	to 5.5 v (unless otherwise specified)

Test Conditions (UA)	Test Conditions (SO)	OUT	
B < B <sub>RP</sub>	$B > B_{RP}$	High	
$B > B_{OP}$	B < B <sub>OP</sub>	Low	

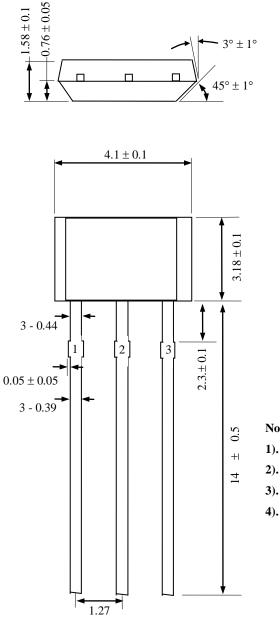
The SOT-23 device is reversed from the UA package. The SOT-23 output transistor will be turned on(drops low) in the presence of a sufficiently strong North pole magnetic field applied to the marked face and turned off(hoists high) in the presence of a sufficiently strong South pole magnetic field.

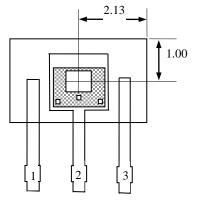




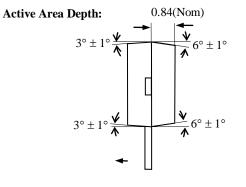
### **Package Information**

#### Package UA, 3-Pin SIP:





Sensor Location



Notes:

1). Controlling dimension : mm ;

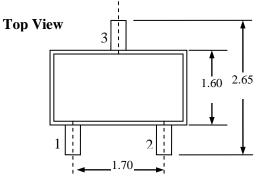
2). Lesds must be free of flash and plating voids ;

3). Do not bend leads within 1 mm of lead to package interface ;

- 4). PINOUT: Pin 1 VDD
  - Pin 2 GND
    - Pin 3 Output

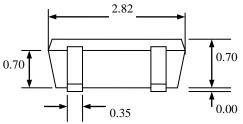


#### Package STT, 3-Pin TSOT-23:

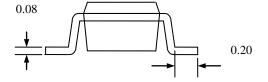


Notes: 1). PINOUT: Pin 1 VDD Pin 2 Output Pin 3 GND 2). All dimensions are in millimeters ;

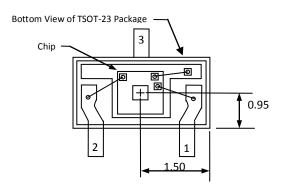
Side View

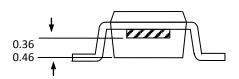


**End View** 



#### Hall Plate Location





### **Ordering Information**

Part No.	Pb-free	Temperature Code	Package Code	Packing
SS542ESTT	YES	-40°C to 85°C	TSOT-23	7-in. reel, 3000 pieces/ reel
SS542EAU	YES	-40°C to 85°C	TO-92	Bulk, 1000 pieces/ bag
SS542KSTT	YES	-40°C to 125°C	TSOT-23	7-in. reel, 3000 pieces/ reel
SS542KAU	YES	-40°C to 125°C	TO-92	Bulk, 1000 pieces/ bag
SS542LSTT	YES	-40°C to 150°C	TSOT-23	7-in. reel, 3000 pieces/ reel
SS542LAU	YES	-40°C to 150°C	TO-92	Bulk, 1000 pieces/ bag